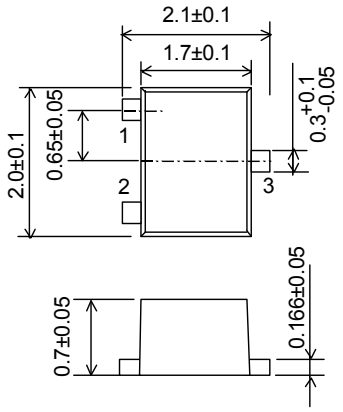
TOSHIBA Field Effect Transistor Silicon P Channel MOS Type

SSM3J36TU

○ Power Management Switches

- 1.5-V drive
- Low ON-resistance: R_{on} = 3.60 Ω (max) (@V_{GS} = -1.5 V)
  : R_{on} = 2.70 Ω (max) (@V_{GS} = -1.8 V)
  : R_{on} = 1.60 Ω (max) (@V_{GS} = -2.8 V)
  : R_{on} = 1.31 Ω (max) (@V_{GS} = -4.5 V)

Unit: mm



UFM	1: Gate 2: Source 3: Drain
JEDEC	—
JEITA	—
TOSHIBA	2-2U1A

Weight: 6.6 mg (typ.)

Absolute Maximum Ratings (Ta = 25 °C)

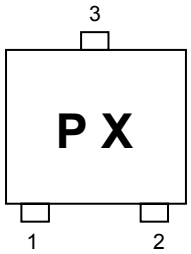
Characteristics		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	-20	V
Gate-source voltage		V_{GSS}	±8	V
Drain current	DC	I_D	-330	mA
	Pulse	I_{DP}	-660	
Drain power dissipation		P_D (Note1)	500	mW
		P_D (Note2)	800	
Channel temperature		T_{ch}	150	°C
Storage temperature range		T_{stg}	−55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/ “Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

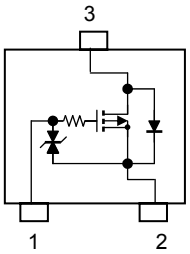
Note1: Mounted on an FR4 board
(25.4 mm × 25.4 mm × 1.6 mm, Cu Pad: 645 mm^2)

Note2: Mounted on a ceramic board.
(25.4 mm × 25.4 mm × 0.8 mm, Cu Pad: 645 mm^2)

Marking



Equivalent Circuit (top view)



Handling Precaution

When handling individual devices (which are not yet mounted on a circuit board), ensure that the environment is protected against static electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Usage Considerations

Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below −1 mA for the SSM3J36TU). Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th}, and $V_{GS(off)}$ must be lower than V_{th}. This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$. Take into consideration when using the device.

Start of commercial production
2008-06

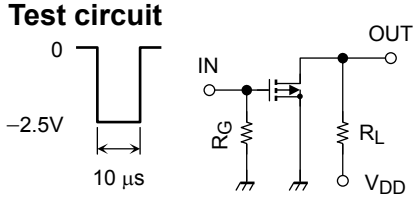
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Conditions	Min	Typ.	Max	Unit
Drain-source breakdown voltage		$V_{(BR)\ DSS}$	I_D = -1 mA, V_{GS} = 0 V	-20	—	—	V
		$V_{(BR)\ DSX}$	I_D = -1 mA, V_{GS} = 8 V	-12	—	—	
Drain cutoff current		I_{DSS}	V_{DS} = -16 V, V_{GS} = 0 V	—	—	-10	μA
Gate leakage current		I_{GSS}	V_{GS} = ±8 V, V_{DS} = 0 V	—	—	±1	μA
Gate threshold voltage		V_{th}	V_{DS} = -3 V, I_D = -1 mA	-0.3	—	-1.0	V
Forward transfer admittance		$\|Y_{fs}\|$	V_{DS} = -3 V, I_D = -100mA (Note3)	190	—	—	mS
Drain-source ON-resistance		$R_{DS\ (ON)}$	I_D = -100mA, V_{GS} = -4.5 V (Note3)	—	0.95	1.31	Ω
			I_D = -80mA, V_{GS} = -2.8 V (Note3)	—	1.22	1.60	
			I_D = -40mA, V_{GS} = -1.8 V (Note3)	—	1.80	2.70	
			I_D = -30mA, V_{GS} = -1.5 V (Note3)	—	2.23	3.60	
Input capacitance		C_{iss}	V_{DS} = -10 V, V_{GS} = 0 V, f = 1 MHz	—	43	—	pF
Output capacitance		C_{oss}		—	10.3	—	
Reverse transfer capacitance		C_{rss}		—	6.1	—	
Total Gate Charge		Q_g	V_{DS} = -10 V, I_{DS}= -330mA V_{GS} = -4 V	—	1.2	—	nC
Gate−Source Charge		Q_{gs}		—	0.85	—	
Gate−Drain Charge		Q_{gd}		—	0.35	—	
Switching time	Turn-on time	t_{on}	V_{DD} = -10 V, I_D = -100mA V_{GS} = 0 to -2.5 V, R_G = 50Ω	—	90	—	ns
	Turn-off time	t_{off}		—	200	—	
Drain-source forward voltage		V_{DSF}	I_D =330mA, V_{GS} = 0 V (Note3)	—	0.88	1.2	V

Note3: Pulse test

Switching Time Test Circuit

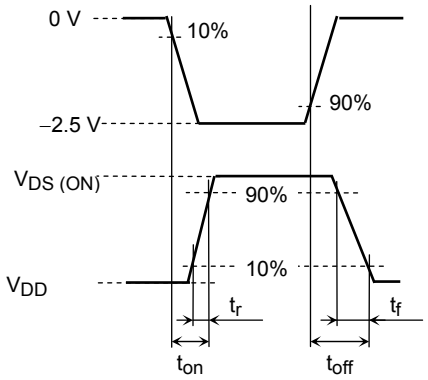
(a) Test circuit



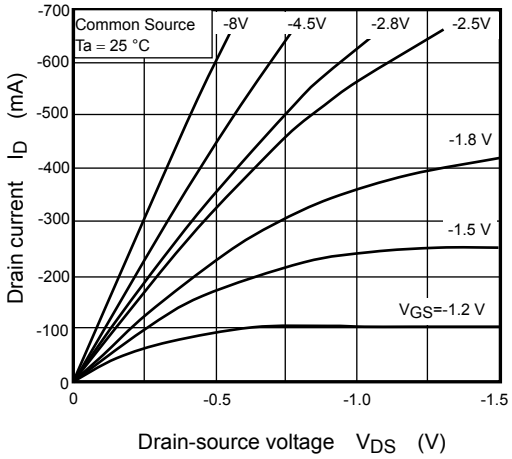
V_{DD} = −10 V
Duty ≤ 1%
V_{IN}: t_r, t_f < 5 ns
(Z_{out} = 50 Ω)
Common Source
Ta = 25°C

(b) V_{IN}

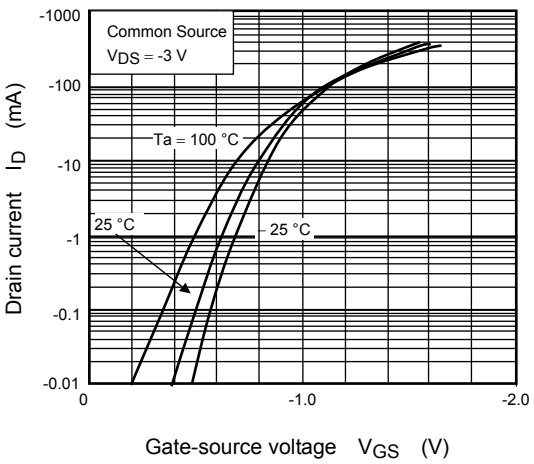
(c) V_{OUT}



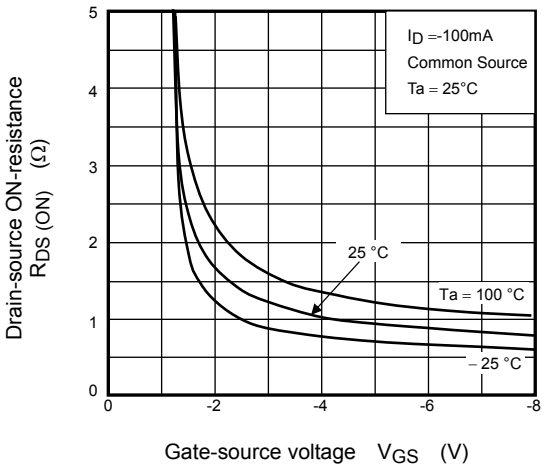
$I_D - V_{DS}$



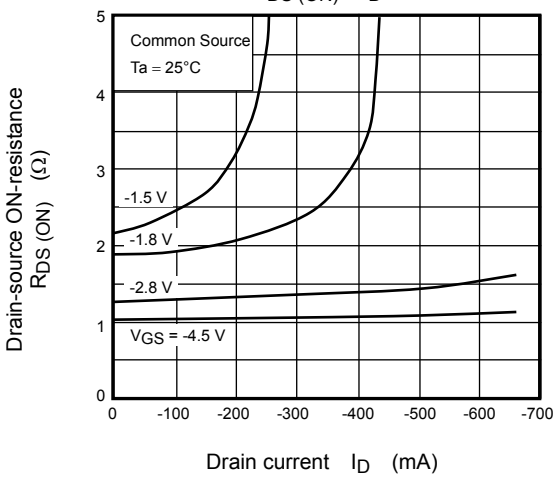
$I_D - V_{GS}$



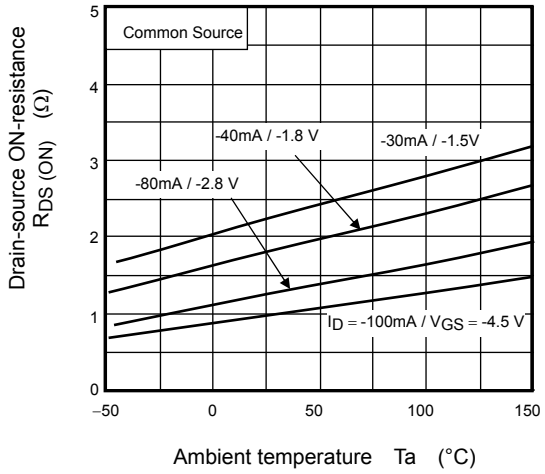
$R_{DS\ (ON)} - V_{GS}$



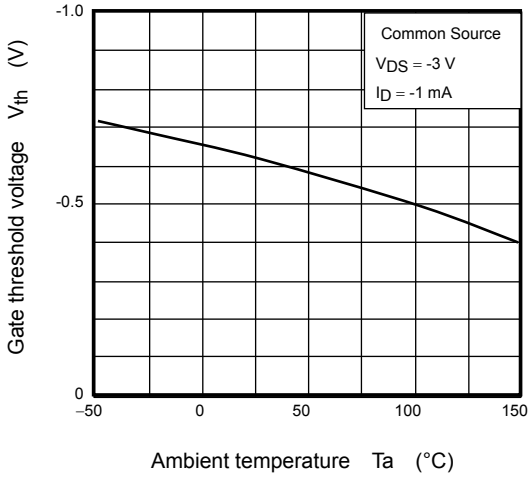
$R_{DS\ (ON)} - I_D$

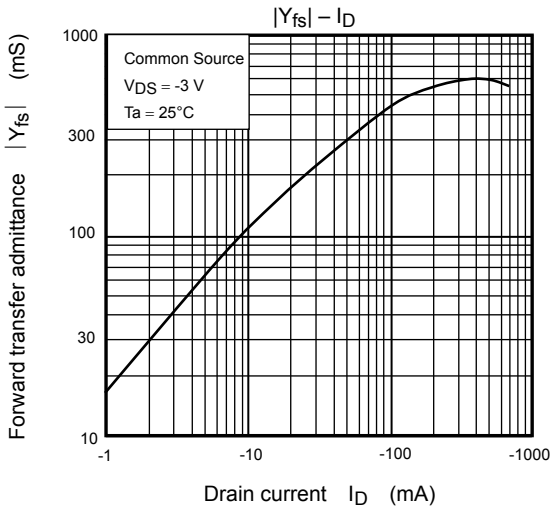


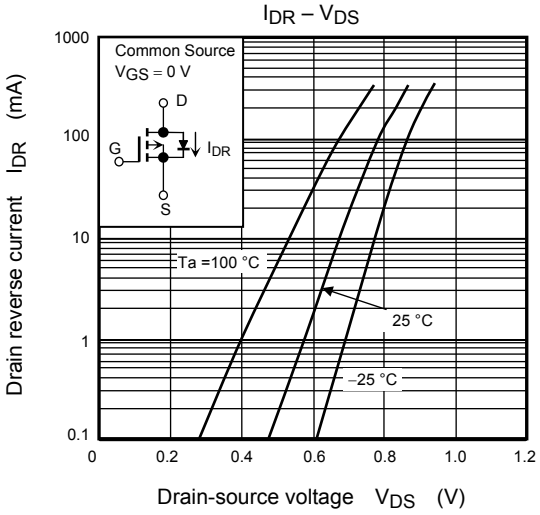
$R_{DS\ (ON)} - Ta$

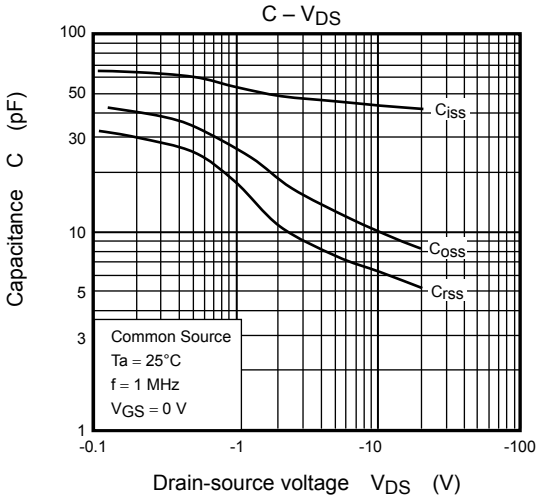


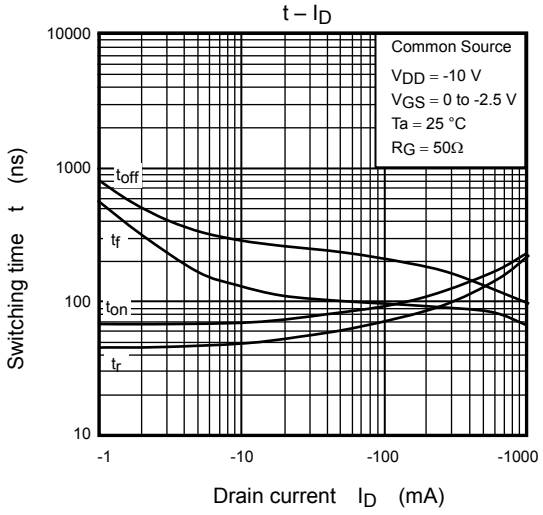
$V_{th} - Ta$

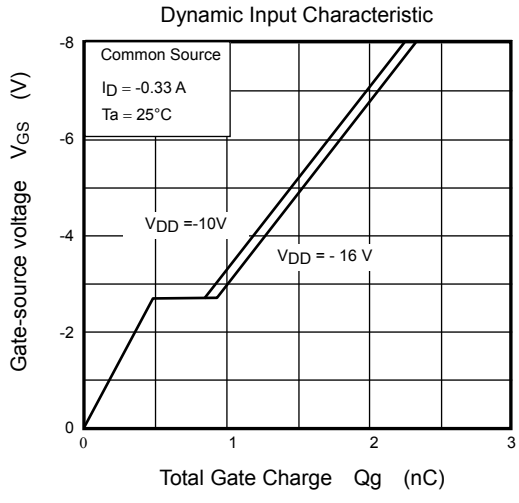


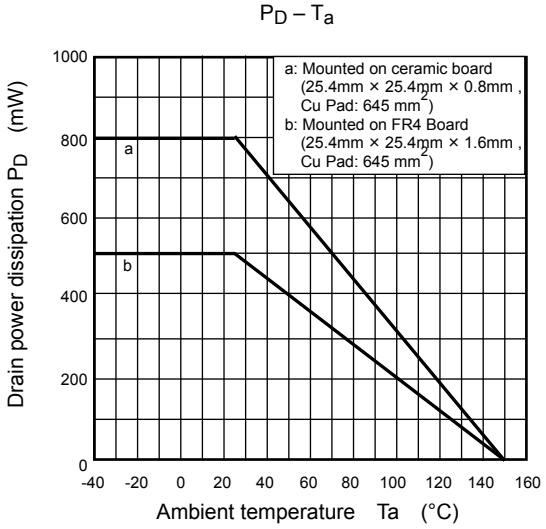

|Yfs| – ID
Common Source
VDS = -3 V
Ta = 25°C
Forward transfer admittance |Yfs| (mS)
Drain current ID (mA)
1000
300
100
30
10
-1
-10
-100
-1000


IDR – VDS
Common Source
VGS = 0 V
D
G
S
IDR
Ta =100 °C
25 °C
−25 °C
Drain reverse current IDR (mA)
Drain-source voltage VDS (V)
1000
100
10
1
0.1
0
0.2
0.4
0.6
0.8
1.0
1.2


C – VDS
Ciss
Coss
Crss
Common Source
Ta = 25°C
f = 1 MHz
VGS = 0 V
Capacitance C (pF)
Drain-source voltage VDS (V)
100
50
30
10
5
3
1
-0.1
-1
-10
-100


t – ID
Common Source
VDD = -10 V
VGS = 0 to -2.5 V
Ta = 25 °C
RG = 50Ω
toff
tf
ton
tr
Switching time t (ns)
Drain current ID (mA)
10000
1000
100
10
-1
-10
-100
-1000


Dynamic Input Characteristic
Common Source
ID = -0.33 A
Ta = 25°C
VDD =-10V
VDD = - 16 V
Gate-source voltage VGS (V)
Total Gate Charge Qg (nC)
-8
-6
-4
-2
0
0
1
2
3


PD – Ta
a: Mounted on ceramic board
(25.4mm × 25.4mm × 0.8mm ,
Cu Pad: 645 mm2)
b: Mounted on FR4 Board
(25.4mm × 25.4mm × 1.6mm ,
Cu Pad: 645 mm2)
a
b
Drain power dissipation PD (mW)
Ambient temperature Ta (°C)
1000
800
600
400
200
0
-40
-20
0
20
40
60
80
100
120
140
160

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